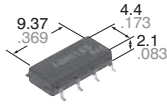


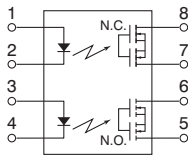
Both NO and NC contacts incorporated in a small SOP8-pin package

PhotoMOS[®] GU SOP Form A & B (AQW610S)



[CAD Data](#)

mm inch

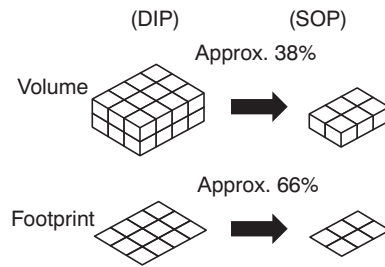


FEATURES

1. Normally open and normally closed contacts in a SOP package
 The device comes in a miniature SOP measuring (W) 4.4 × (L) 9.37 × (H) 2.1 mm (W) .173× (L) .369× (H) .083 inch — approx. 38% of the volume and 66% of the footprint size of DIP type.

4. Controls low-level analog signals
 PhotoMOS relays feature extremely low closed-circuit offset voltage to enable control of low-level analog signals without distortion

5. Low-level off-state leakage current of max. 1 μA



2. 60V type couples high capacity (0.45A) with low on-resistance (typ. 1Ω) (AQW612S).

3. Applicable for 1 Form A 1 Form B use as well as two independent 1 Form A and 1 Form B use

TYPICAL APPLICATIONS

- Power supply
- Measuring equipment
- Security equipment
- Telephone equipment
- Computer input machines
- Industrial robots
- High-speed inspection machines

TYPES

	Output rating*		Package	Part No.			Packing quantity	
	Load voltage	Load current		Tube packing style	Tape and reel packing style		Tube	Tape and reel
					Picked from the 1/2/3/4-pin side	Picked from the 5/6/7/8-pin side		
AC/DC dual use	60V	450mA	SOP8-pin	AQW612S	AQW612SX	AQW612SZ	1 tube contains: 50 pcs. 1 batch contains: 1,000 pcs.	1,000 pcs.
	350V	100mA		AQW610S	AQW610SX	AQW610SZ		

* Indicate the peak AC and DC values.
 Note: The packing style indicator "X" or "Z" are not marked on the relay.

RATING

1. Absolute maximum ratings (Ambient temperature: 25°C 77°F)

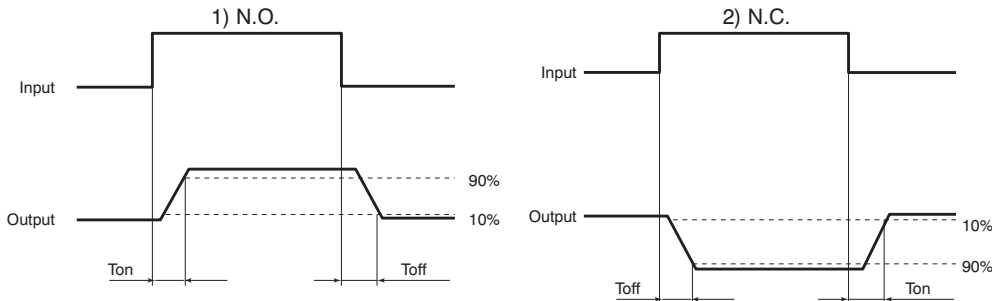
Item		Symbol	AQW612S	AQW610S	Remarks
Input	LED forward current	I _F	50 mA		
	LED reverse voltage	V _R	5 V		
	Peak forward current	I _{FP}	1 A		f = 100 Hz, Duty factor = 0.1%
	Power dissipation	P _{in}	75 mW		
Output	Load voltage (peak AC)	V _L	60 V	350 V	
	Continuous load current	I _L	0.45 A (0.55 A)	0.1 A (0.13 A)	Peak AC, DC (): in case of using only 1a or 1b, 1 channel
	Peak load current	I _{peak}	1.5 A	0.3 A	100 ms (1 shot), V _L = DC
	Power dissipation	P _{out}	600 mW		
Total power dissipation		P _T	650 mW		
I/O isolation voltage		V _{iso}	1,500 V AC		
Temperature limits	Operating	T _{opr}	-40°C to +85°C -40°F to +185°F		Non-condensing at low temperatures
	Storage	T _{stg}	-40°C to +100°C -40°F to +212°F		

GU SOP Form A & B (AQW61OS)

2. Electrical characteristics (Ambient temperature: 25°C 77°F)

Item		Symbol	AQW612S	AQW610S	Condition	
Input	LED operate current	Typical	0.9 mA		I _L = Max.	
		Maximum	3 mA			
	LED reverse current	Minimum	0.4 mA		I _L = Max.	
		Typical	0.8 mA			
LED dropout voltage	Typical	1.25 V (1.14 V at I _F = 5 mA)		I _F = 50 mA		
	Maximum	1.5 V				
Output	On resistance	Typical	1 Ω	18 Ω	I _F = 5 mA (N.O.) I _F = 0 mA (N.C.) I _L = Max. Within 1 s on time	
		Maximum	2.5 Ω	25 Ω		
	Off state leakage current	Maximum	1 μA		I _F = 0 mA (N.O.) I _F = 5 mA (N.C.) V _L = Max.	
Transfer characteristics	Operate time*	Typical	T _{on} (N.O.)	0.65 ms (N.O.), 0.9 ms (N.C.)	0.28 ms (N.O.), 0.52 ms (N.C.)	I _F = 0 mA → 5 mA I _L = Max.
		Maximum	T _{off} (N.C.)	3.0 ms		
	Reverse time*	Typical	T _{off} (N.O.)	0.08 ms (N.O.), 0.2 ms (N.C.)		I _F = 5 mA → 0 mA I _L = Max.
		Maximum	T _{on} (N.C.)	1.0 ms		
	I/O capacitance	Typical	C _{iso}		0.8 pF	
	Maximum			1.5 pF		V _B = 0 V
Initial I/O isolation resistance	Minimum	R _{iso}	1,000 MΩ		500 V DC	

*Operate/Reverse time



RECOMMENDED OPERATING CONDITIONS

Please obey the following conditions to ensure proper relay operation and resetting.

Item	Symbol	Recommended value	Unit
Input LED current	I _F	5	mA

■ Dimensions

■ Schematic and Wiring Diagrams

■ Cautions for Use

■ These products are not designed for automotive use.

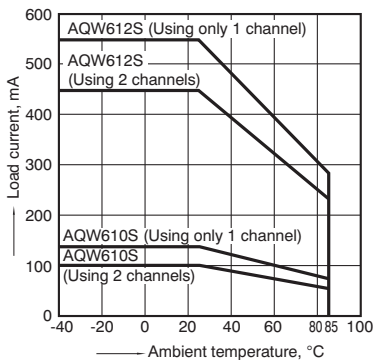
If you are considering to use these products for automotive applications, please contact your local Panasonic technical representative.

Please refer to our information on [PhotoMOS Relays for Automotive Applications](#).

REFERENCE DATA

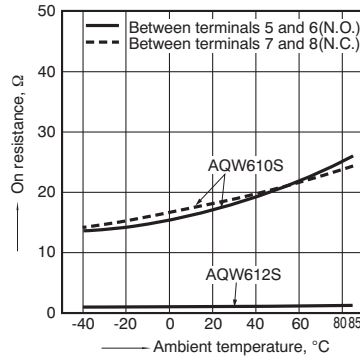
1. Load current vs. ambient temperature characteristics

Allowable ambient temperature: -40°C to +85°C
-40°F to +185°F



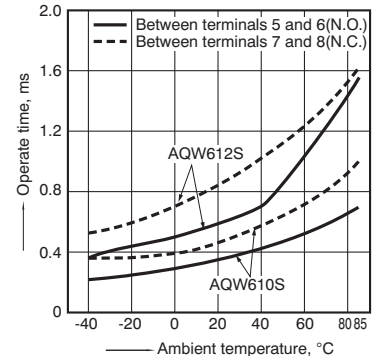
2. On resistance vs. ambient temperature characteristics

Measured portion: between terminals 5 and 6, 7 and 8; LED current: 5 mA; Load voltage: Max. (DC); Continuous load current: Max. (DC)



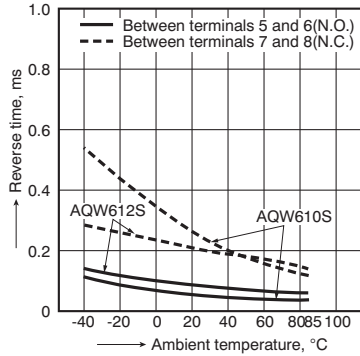
3. Operate time vs. ambient temperature characteristics

LED current: 5 mA; Load voltage: Max. (DC); Continuous load current: Max. (DC)



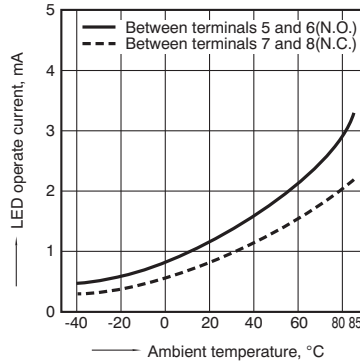
4. Reverse time vs. ambient temperature characteristics

LED current: 5 mA; Load voltage: Max. (DC);
Continuous load current: Max. (DC)



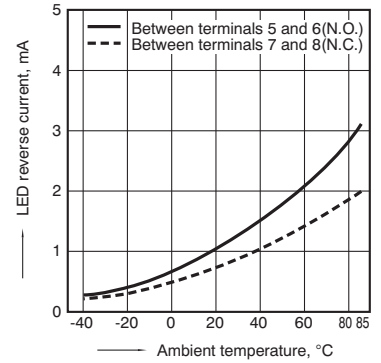
5. LED operate current vs. ambient temperature characteristics

Load voltage: Max. (DC);
Continuous load current: Max. (DC)



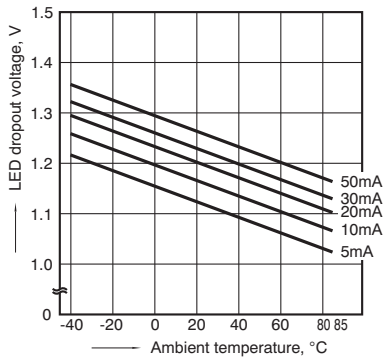
6. LED reverse current vs. ambient temperature characteristics

Load voltage: Max. (DC);
Continuous load current: Max. (DC)



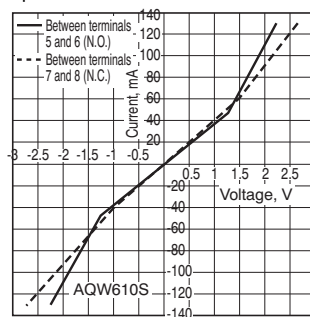
7. LED dropout voltage vs. ambient temperature characteristics

LED current: 5 to 50 mA



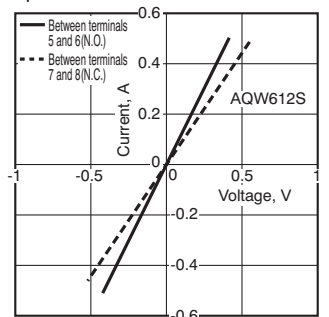
8-(1). Current vs. voltage characteristics of output at MOS portion

Measured portion: between terminals 5 and 6, 7 and 8;
Ambient temperature: 25°C 77°F



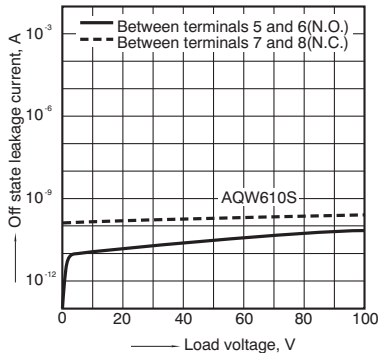
8-(2). Current vs. voltage characteristics of output at MOS portion

Measured portion: between terminals 5 and 6, 7 and 8;
Ambient temperature: 25°C 77°F



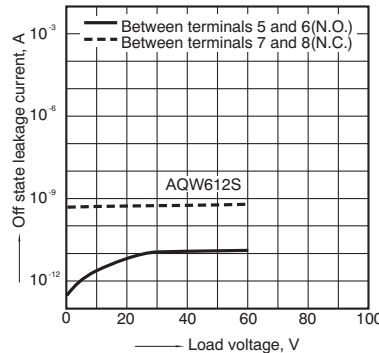
9-(1). Off state leakage current vs. load voltage characteristics

Measured portion: between terminals 5 and 6, 7 and 8;
Ambient temperature: 25°C 77°F



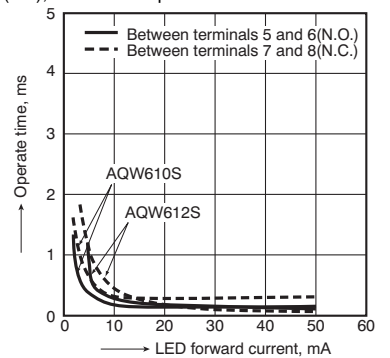
9-(2). Off state leakage current vs. load voltage characteristics

Measured portion: between terminals 5 and 6, 7 and 8;
Ambient temperature: 25°C 77°F



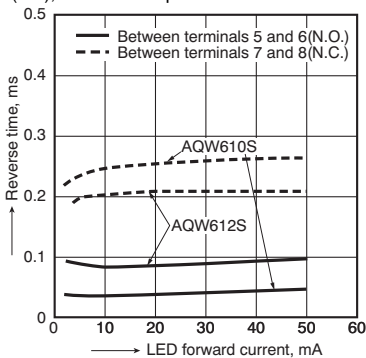
10. Operate time vs. LED forward current characteristics

Measured portion: between terminals 5 and 6, 7 and 8;
Load voltage: Max. (DC); Continuous load current: Max. (DC); Ambient temperature: 25°C 77°F



11. Reverse time vs. LED forward current characteristics

Measured portion: between terminals 5 and 6, 7 and 8;
Load voltage: Max. (DC); Continuous load current: Max. (DC); Ambient temperature: 25°C 77°F



12. Output capacitance vs. applied voltage characteristics

Measured portion: between terminals 5 and 6, 7 and 8;
Frequency: 1 MHz;
Ambient temperature: 25°C 77°F

